

# Detector R&D for synchrotron facilities

F.J. Iguaz – Journée « La photodetection avec les semiconducteurs »

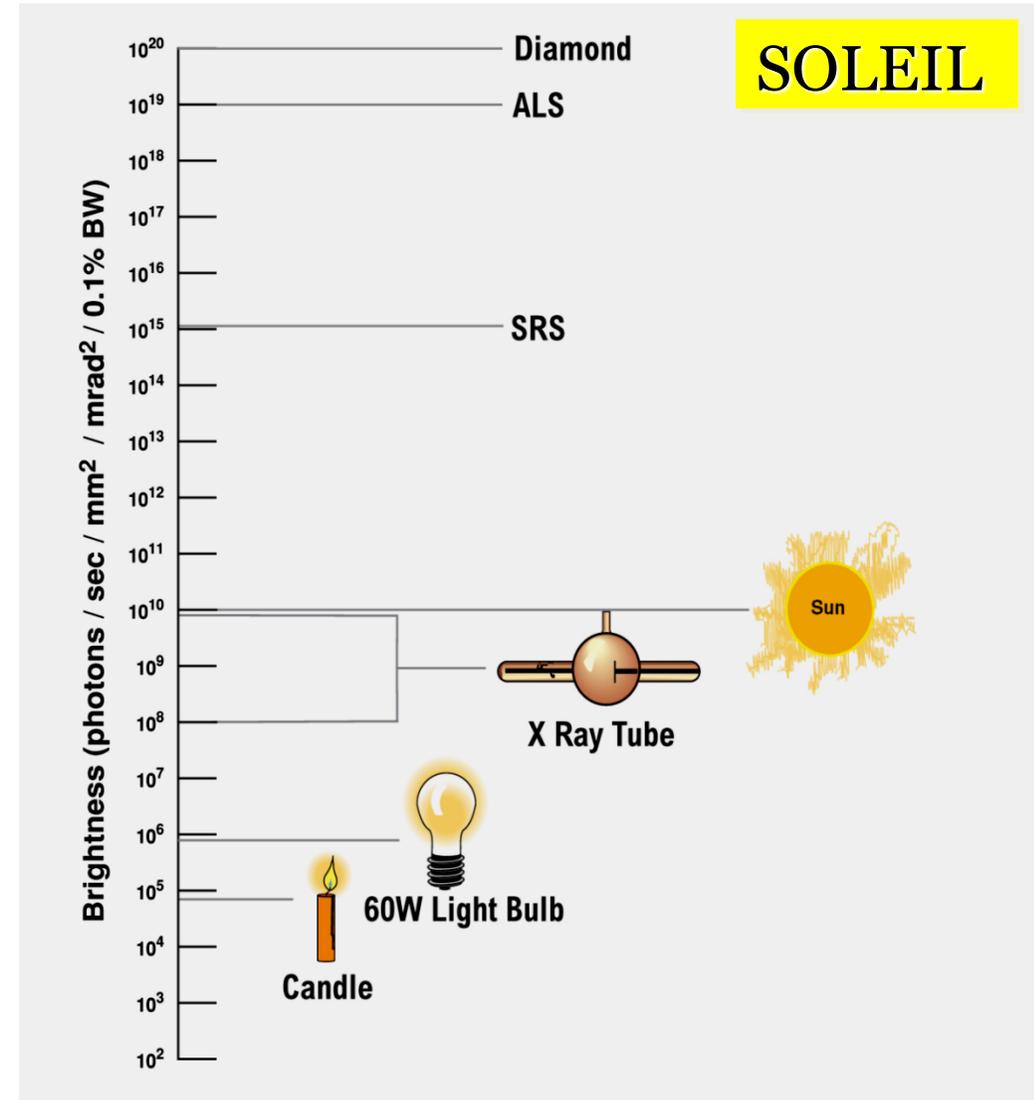
LPSC, Grenoble, 03-04/06/2024 – Ref: EXP-DET24-P023-A

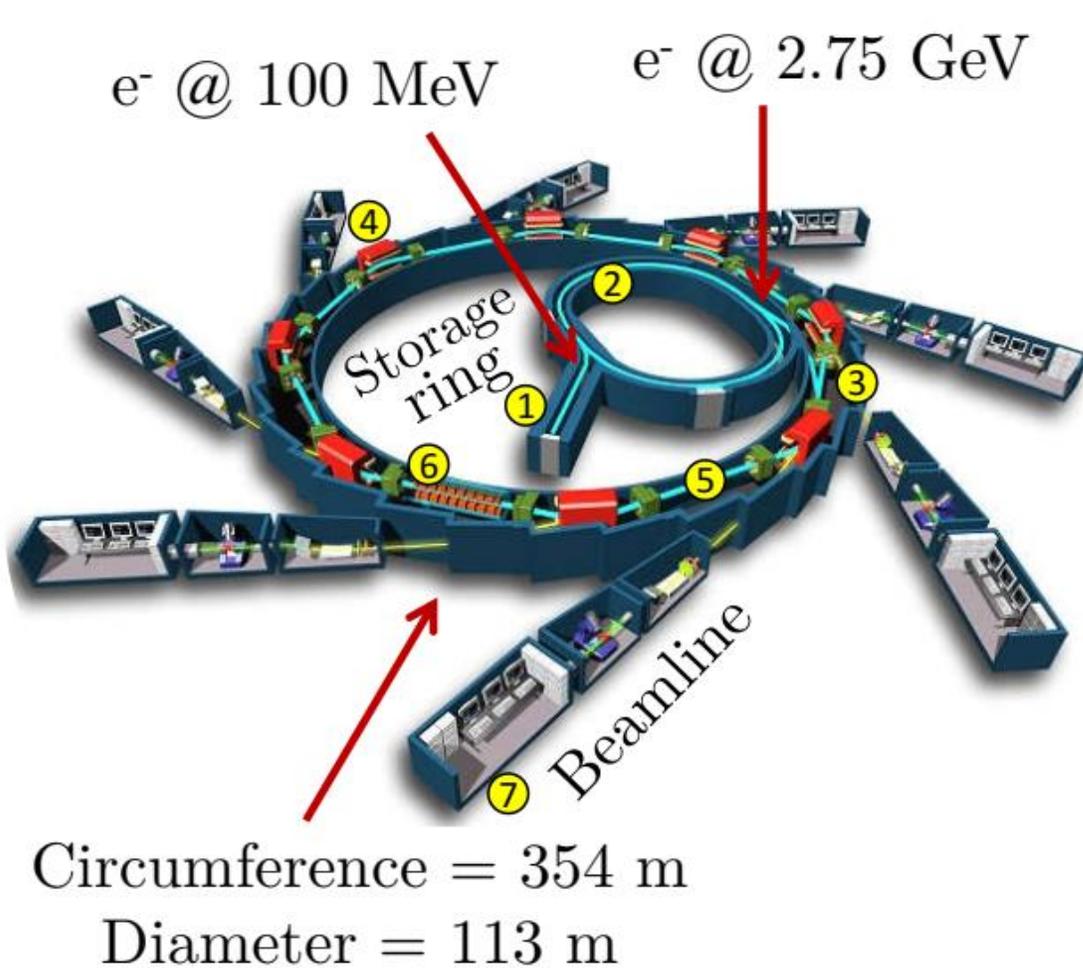
- All material in this presentation come from different sources. >90% are not mine. Please, check references to get more details.
- I thank Ana Torrento for this invitation to give a review talk
- I thank all my SOLEIL detector group colleagues for their work shown here:
  - Marie Andrae, Arkadiusz Dawiec, Kewin Desjardins, Claude Menneglier, Nishu Goyal, Jean Roche
  - Christian Bacchi, Diana Bachiller-Perea, Benjamin Boitrelle, Michel Bordessoule, Brahim Kanouté, Luis Manzanillas, E.A. Mansour, Fabienne Orsini, Elio Sacchetti, Y. Sergent (former)

- Synchrotron radiation, production and facilities
- Experimental techniques, energy range and application
- Overview of semiconductor detectors & new developments:
  - Spectroscopy: Silicon Drift Detectors & multi-element germanium
  - Diffraction: pixelized hybrid detectors, CMOS camera
- Conclusions

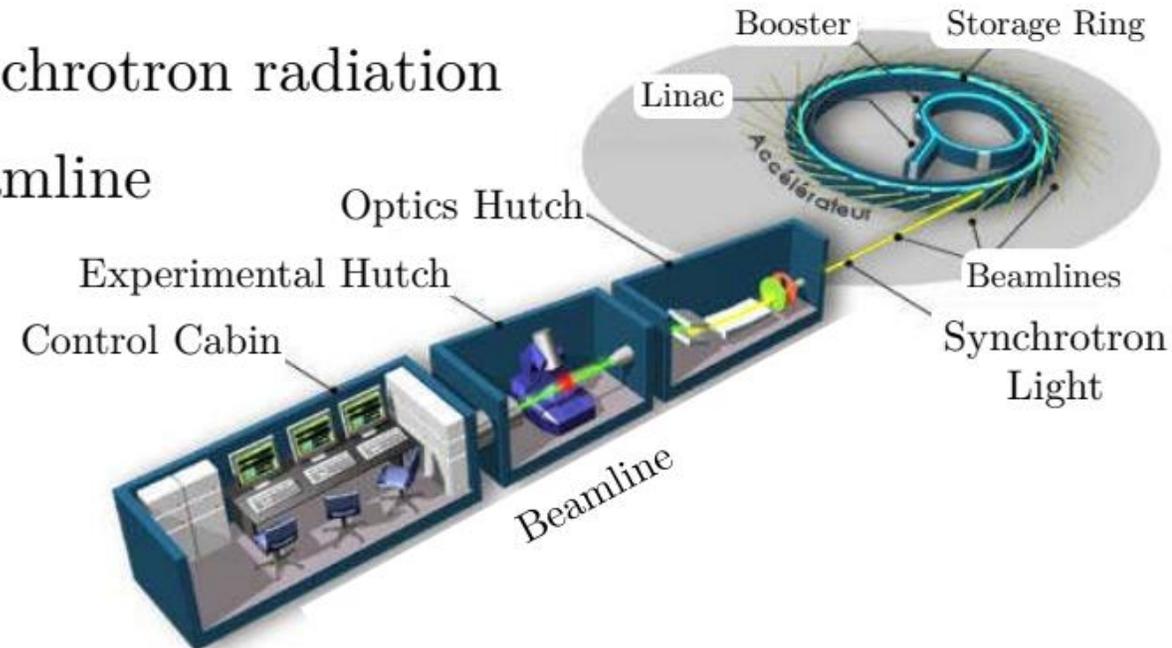
## Synchrotron radiation features:

- Very bright
- Pulsatility (50 ps every 3 ns)
- Polarized
- Adjustable wavelength (broad spectrum)
- Stable (in position and intensity)
- Thin size: 15 $\mu\text{m}$  height and 150  $\mu\text{m}$  width (brush of light)
- Low divergence (microfocusing)





- ① Electron gun + Linac (16 m)
- ② Booster (circular accelerator)
- ③ Injection in the storage ring
- ④ Magnetic devices
- ⑤ RF cavities
- ⑥ Synchrotron radiation
- ⑦ Beamline





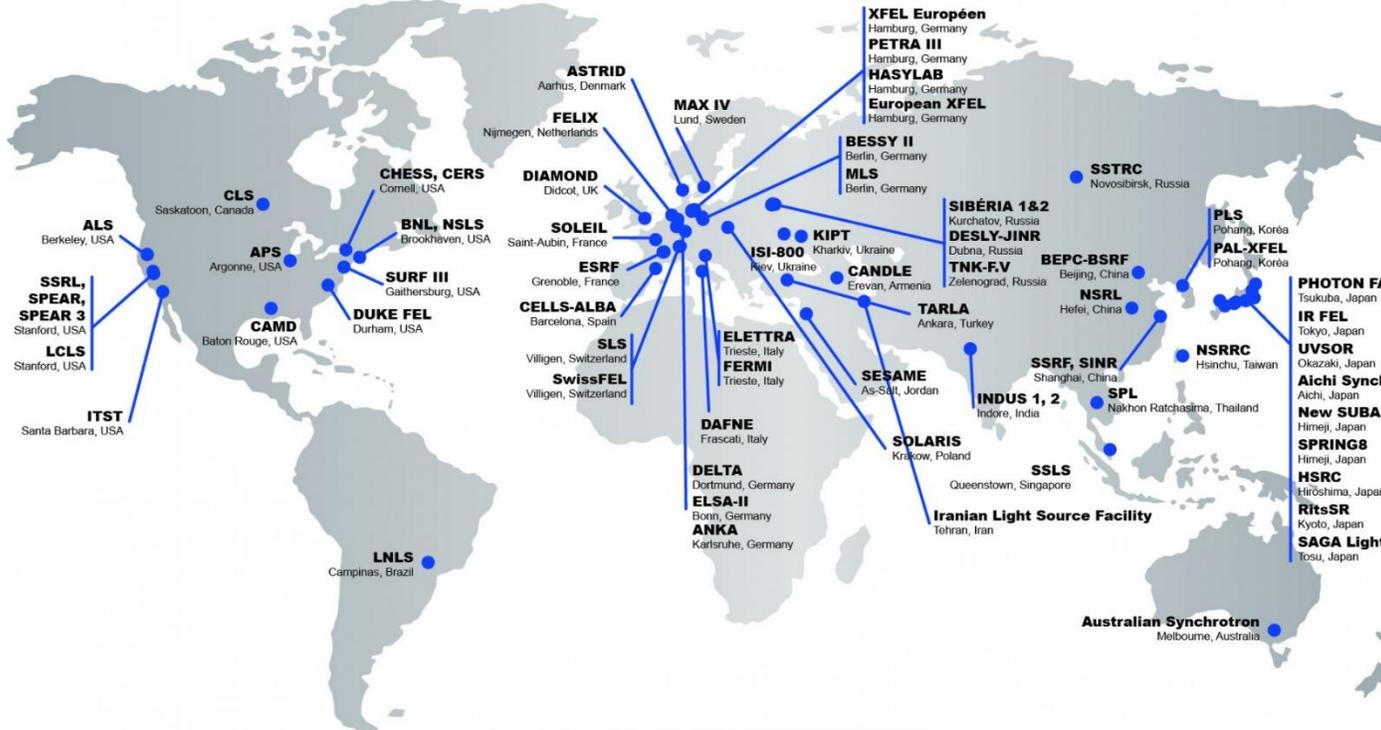
**Barcelona, Spain**



**Grenoble, France**



**Trieste, Italy**



**Ditcot, UK**



**Villigen, Switzerland**



**Jordan**



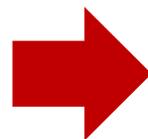
**Melbourne, Australia**



**USA**



**Japan**



**The main part of synchrotron facilities are in Japan, United States & Europe**

## Spectroscopy

XAS, XANES, EXAFS,  
XRF, PES, ...

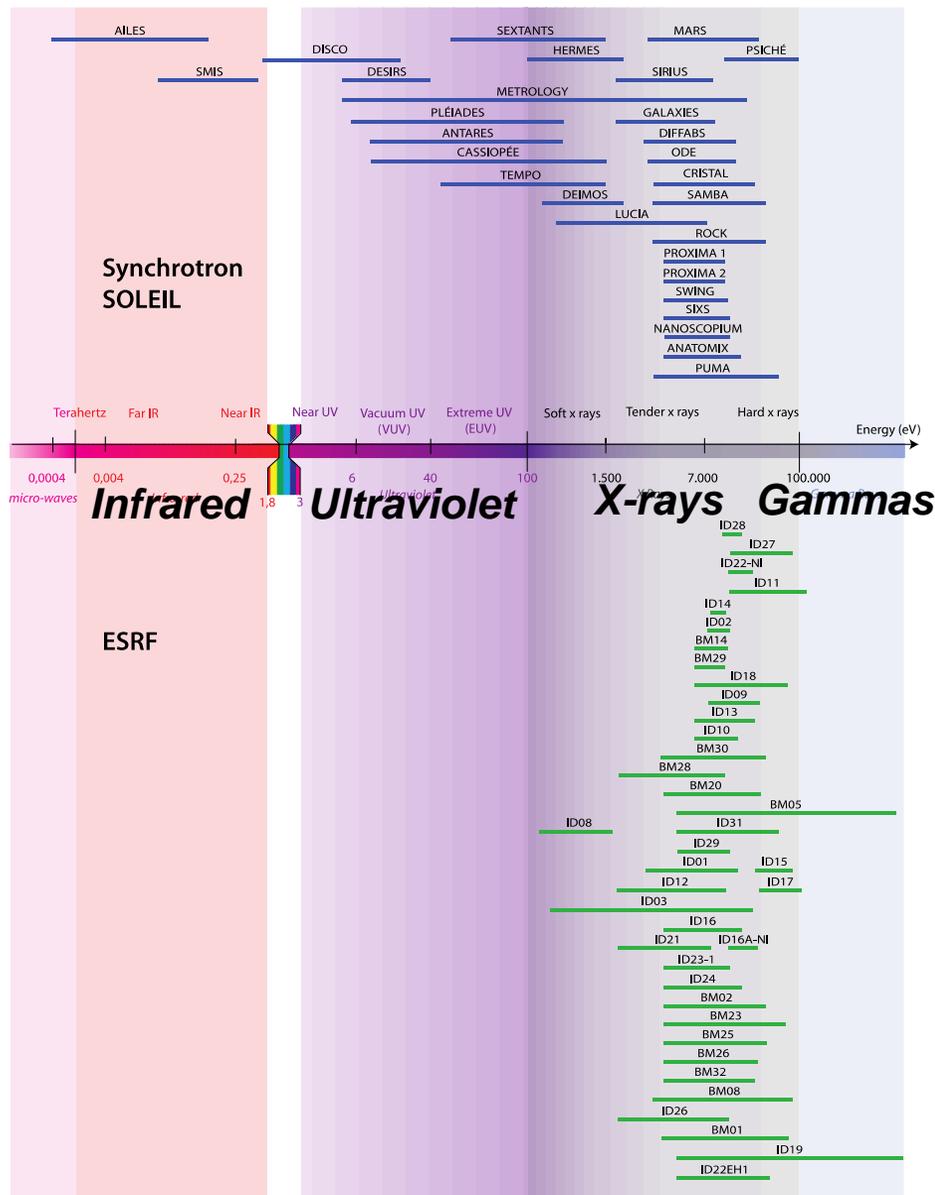
## Scattering

XRD, Laue, SAXS,  
WAXS, GISAXS, XRR,  
IXS/RIXS, XRMS, ...

## Imaging/scanning

CDI, STXM, XCT,  
PCI, CXI, ...

*And time resolved experiments,  
exploiting pulsed beam (~3 ns)*



## Applications



Biology



Medical



Pharmaceutical



Cosmetics



Chemistry



Paleontology  
and Archeology



Energy and  
Environment



Materials



Food



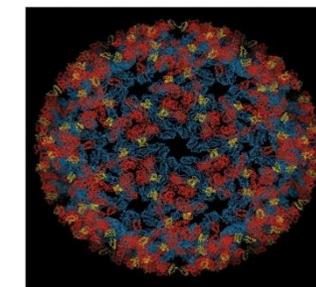
Astrophysics



Geophysics and  
geology



**Small of  
paintings**



**Structure of virus  
Chikungunya**

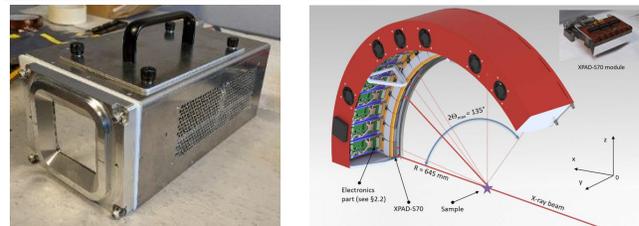
**CMOS or hybrid pixel detectors**  
(X-ray diffraction, phytography, ...)



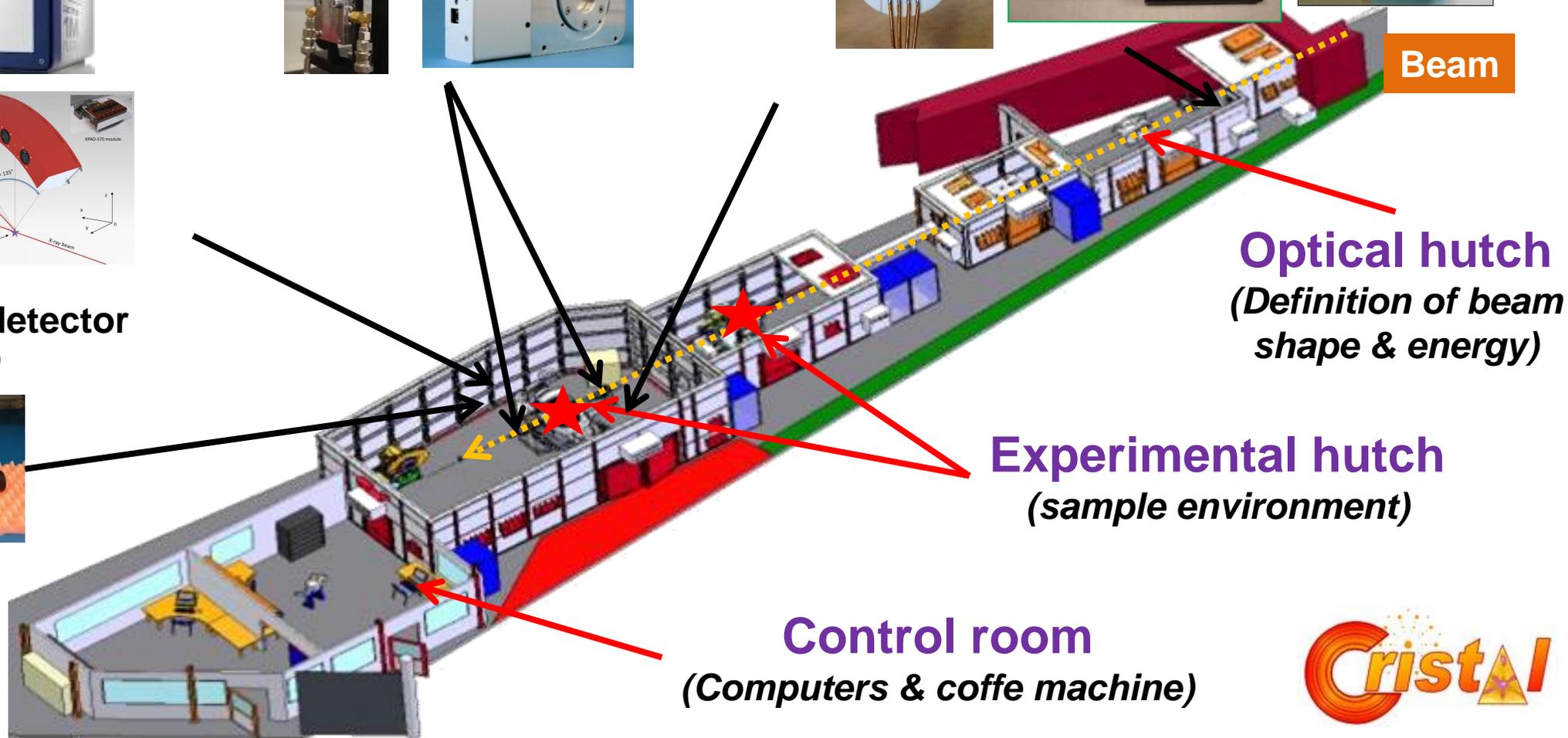
**Diode or ionization chamber**  
(Beam intensity before & after)

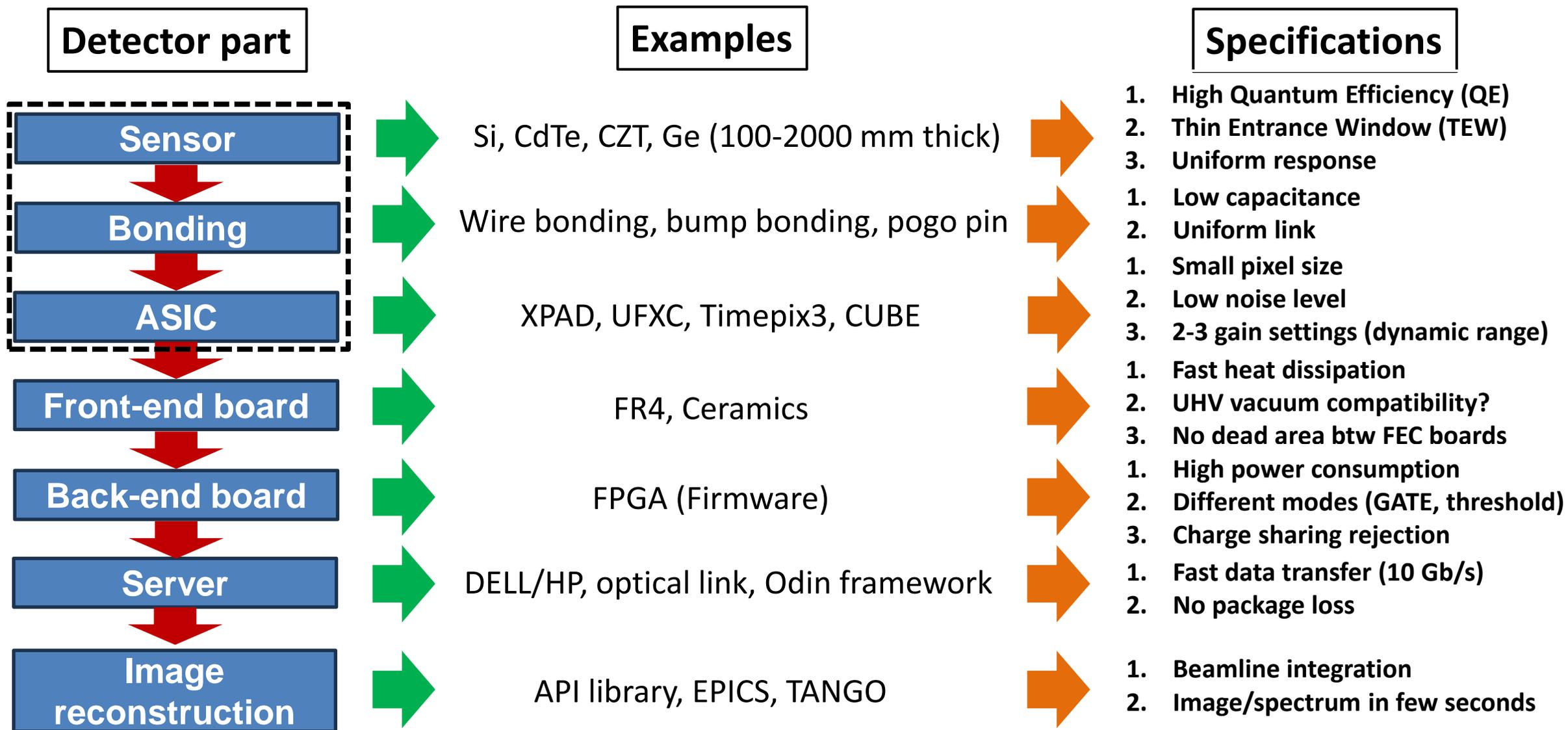


**XBPM, camera, imager**  
(Beam position, intensity & shape)



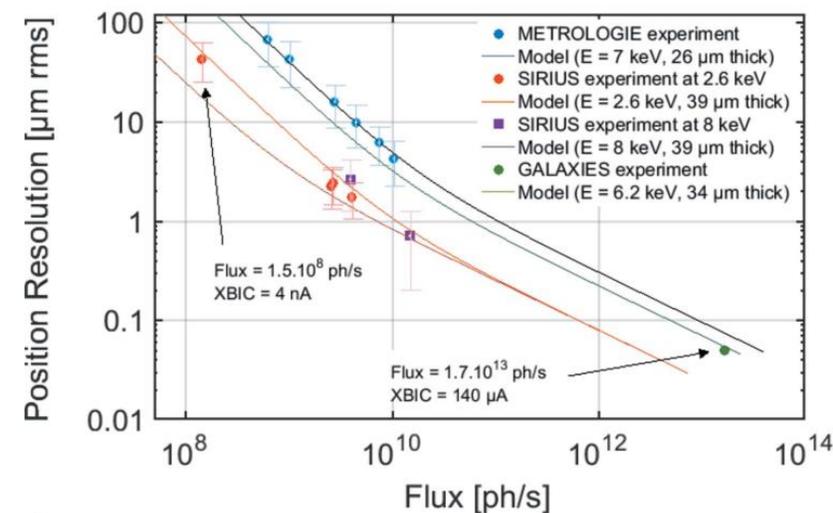
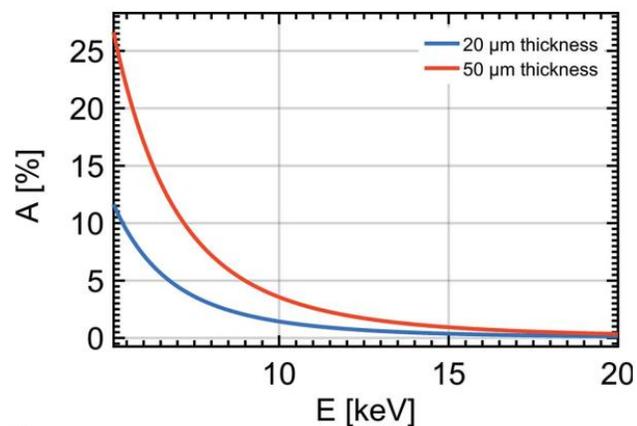
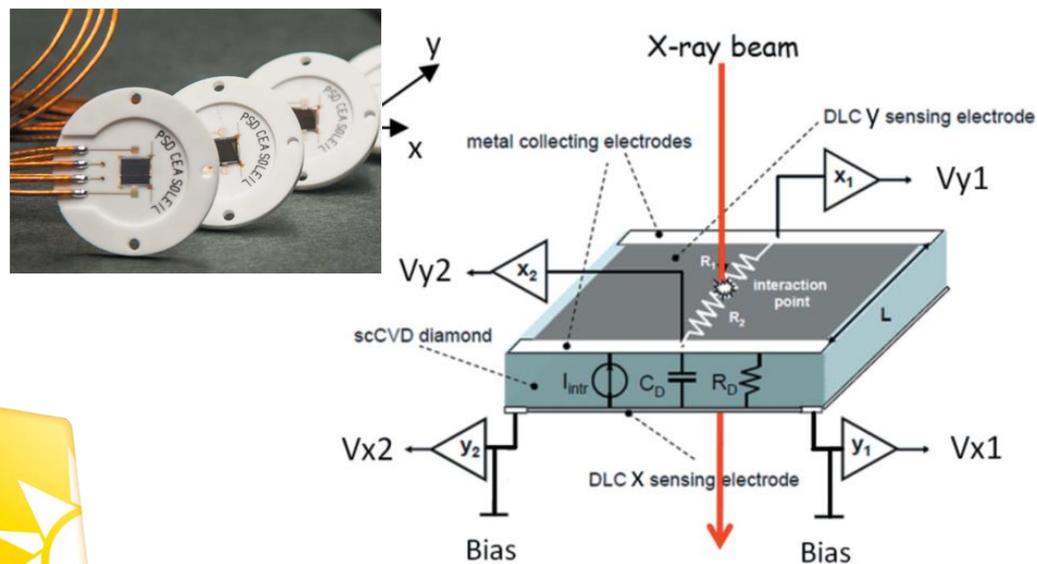
**Energy Dispersive detector**  
(Fluorescence)





K. Desjardins et al., *J. Sync. Rad* 25 (2018) 1-8K. Desjardins et al., *J. Sync. Rad* 21 (2014) 1217-1223

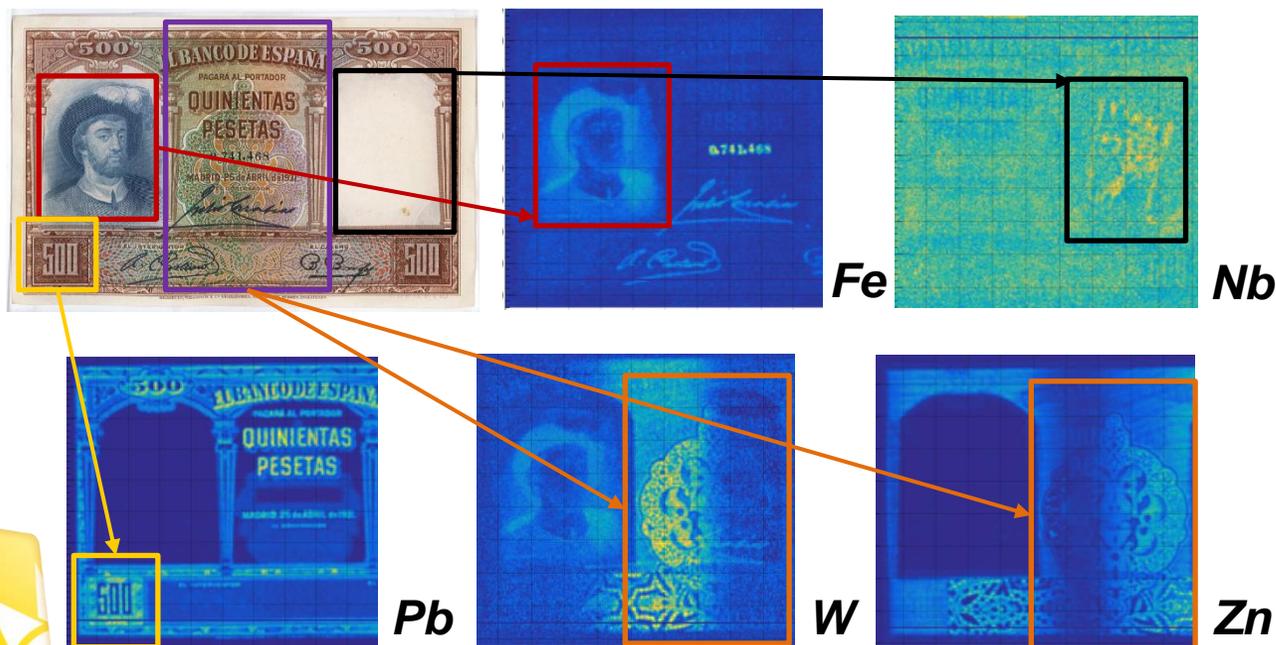
- Beam diagnostic tool, with low beam flux absorption
- Electronics: LOCUM-4M current-to-voltage amplifier + ADC convertor
- Features:
  - CVD diamond, 4.5 mm x 4.5 mm, 20  $\mu\text{m}$  or 50  $\mu\text{m}$  thickness + DLC coating (100 k $\Omega$ , 200 nm)
  - Surface signal variation < 0.7% -> Peak-to-peak thickness difference < 300 nm
  - Position resolution between 50 – 0.05  $\mu\text{m}$ , for fluxes between  $1.5 \times 10^8$  and  $1.7 \times 10^{13}$  ph/s



# Spectroscopy techniques

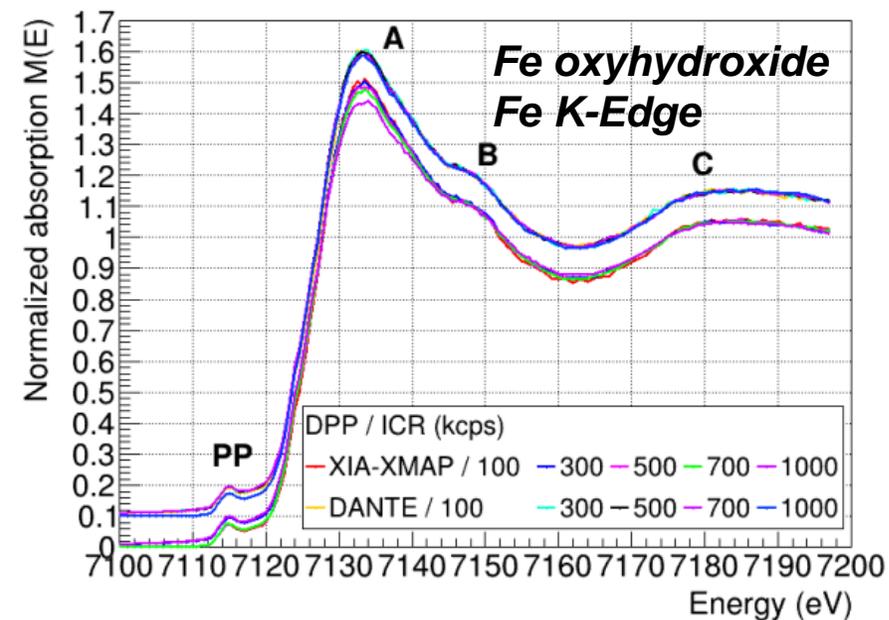
## X-ray Fluorescence (XRF)

- Fluorescence signal of a sample is measured after an excitation by incident X-ray photons at a given energy.
- The energy of the fluorescence signal depends on the element (Fe: 6.4 keV, Pb: 10.5 keV).
- Intensity is proportional to the concentration.
- Combined with a micro-beam, an element map can be collected by scanning the sample position.



## X-ray Absorption Spectroscopy (XAS)

- The absorption coefficient of an element is measured as a function of the energy scan around the ionization threshold.
- The XAS spectrum provides information on:
  - **A,B:** Electronic structure of the excited atom (oxidation state & environment)
  - **C:** Interatomic distance between the excited atom & its neighbours
  - **PP:** Oxidation state of the excited atom

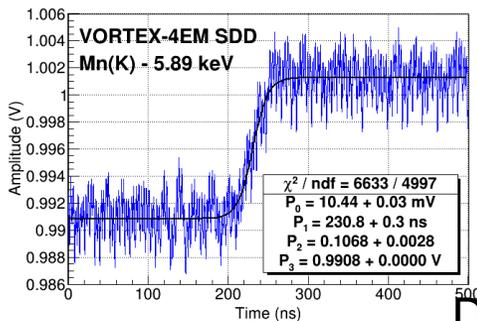
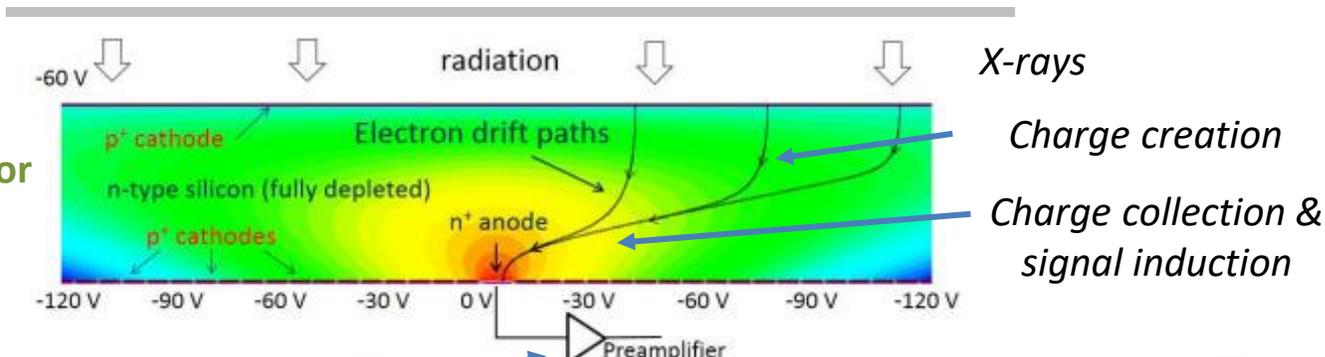


- Counting detectors resolved in energy.
- Linear counting rate between  $10^3$  and  $10^6$  cps
- Types: **Silicon Drift Detectors (SDD)**, multi-element germanium (HPGe), CdTe
- # elements: 1-36. Active surface: 10 to 100 mm<sup>2</sup>, collimated to remove border effects

*P. Rehak et al., NIMA 624 (2010) 260-264*  
*D.M. Schlosser et al., NIMA 624 (2010) 270-276*

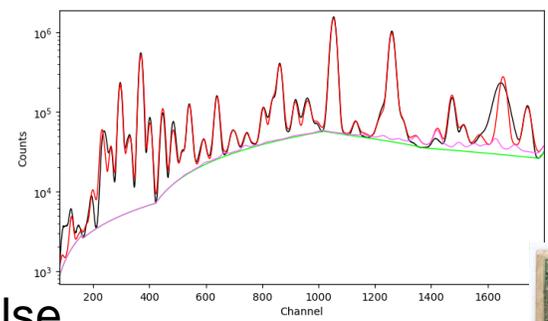
Input window (Be, SPD)

Silicon sensor (450  $\mu$ m)

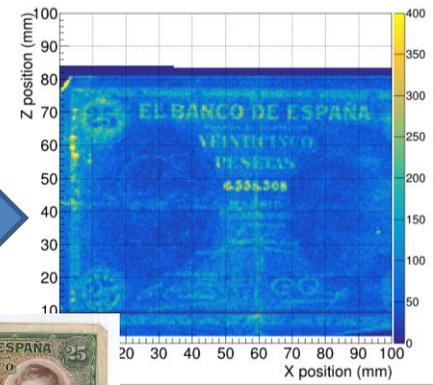


Signal induced by an X-ray

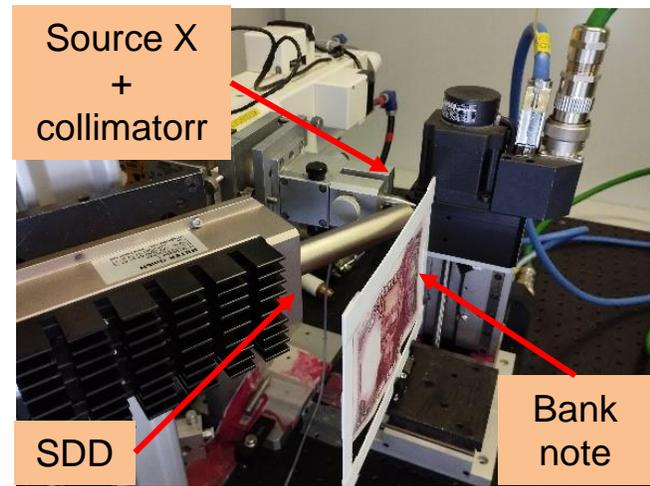
Digital Pulse Processor (XIA-XMAP, FalconX, Xspress3, DANTE)



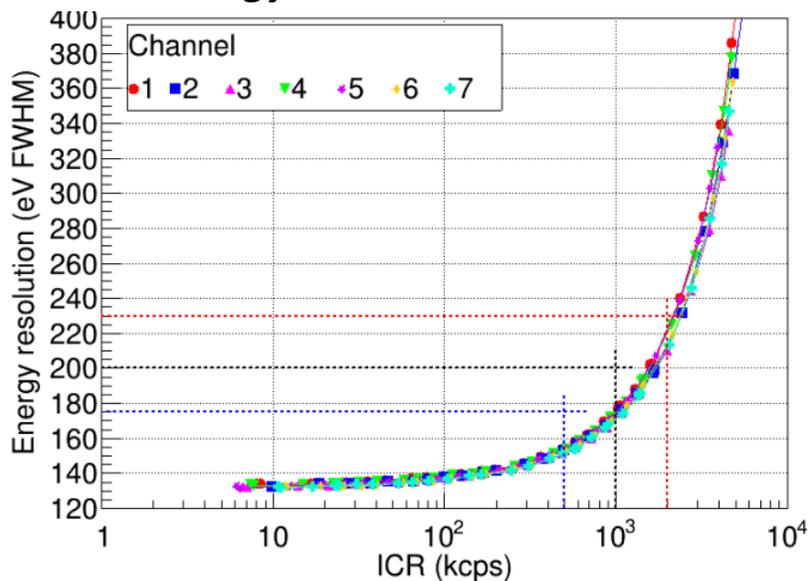
Energy spectrum



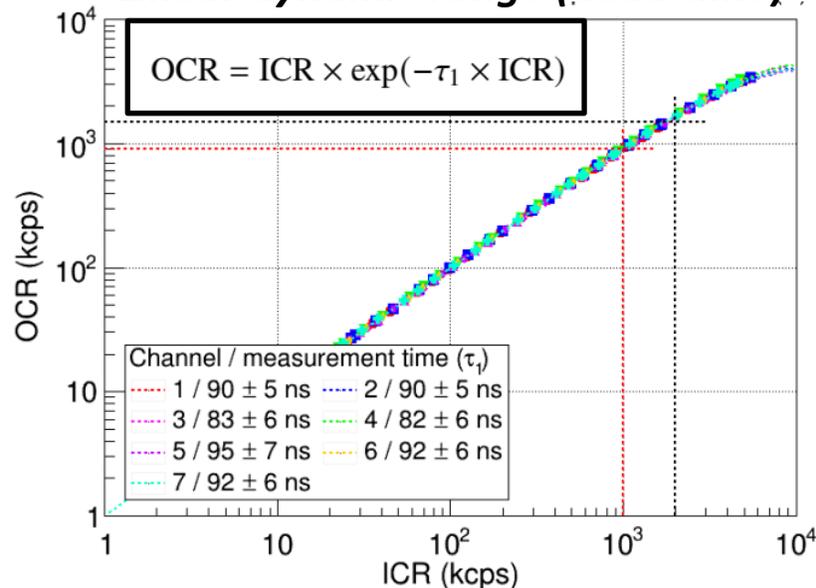
Cartography (Iron distribution)



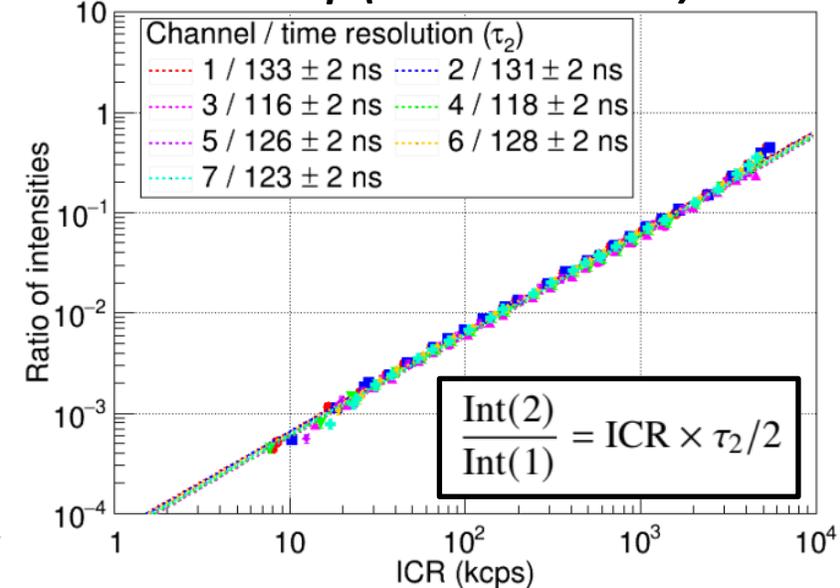
### Energy resolution at 5.9 keV



### Linear dynamic range (dead time)



### Pile-up (resolution time)



## Features for most recent SDD with DPP:

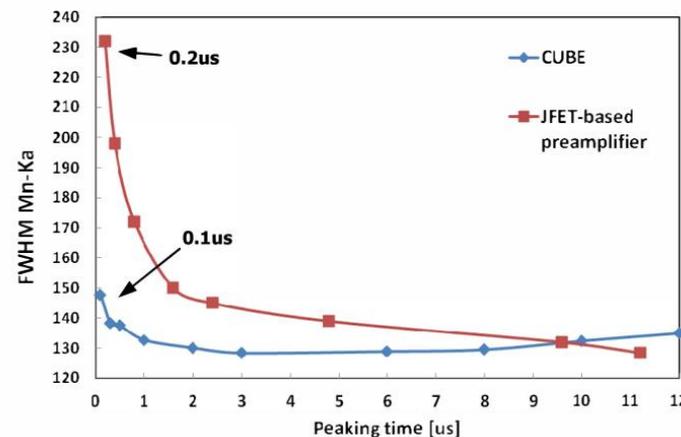
- Signal-to-background (S/B) ratio > 10<sup>3</sup> at 10 kcps
- Energy resolution of 130 eV FWHM at 10 kcps
- Energy resolution < 200 eV FWHM at ICR of 1 Mcps
- Linear dynamic range up to 1 Mcps -> Dead time < 100 ns
- Intensity pile-up peak < 10% up to 1 Mcps -> Resolution ~ 125 ns



**CANBERRA 13EM SDD detector with Xpress3X DPP at SAMBA beamline**

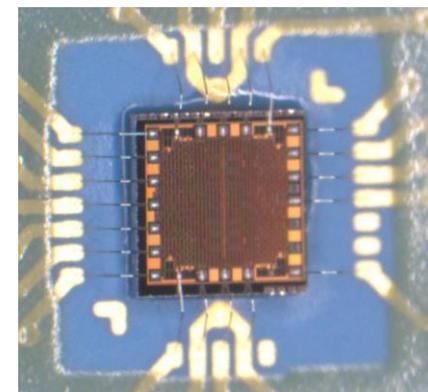
## Detector:

- CUBE ASIC (integrated preamplifier)
- 4 channel CUBE ASIC (for SDD & HPGe)
- **Multi-element monolithic SDD (ARDESIA)**
- Polymer windows (AP2.3) for soft X-rays
- **Zero Beryllium window (90% transmission)**
- Cryo-pulsed refrigerator for Ge detectors



*CUBE performance*

[10.1109/NSSMIC.2011.6154396](https://doi.org/10.1109/NSSMIC.2011.6154396)



*TETRA ASIC for LEAPS-INNOV project*

## Digital Pulse Processors (DPP):

- XIA-FalconX & Xspress3M: Pulse analysis in firmware to extend the linear dynamic range
- DANTE: Intermediate performance & cheaper DPP for multi-element detectors
- Xspress4: Charge sharing event rejection in Ge



*XIA-FalconX*



*DANTE*

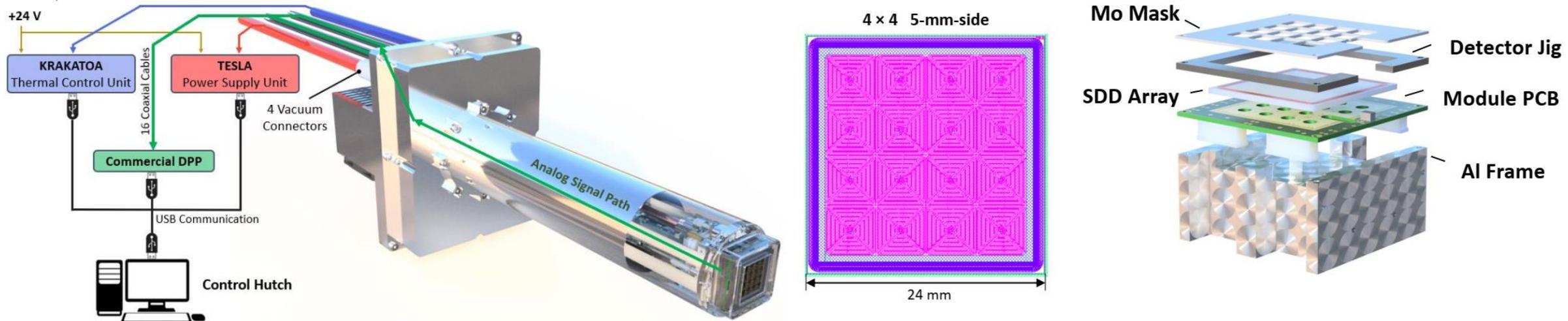


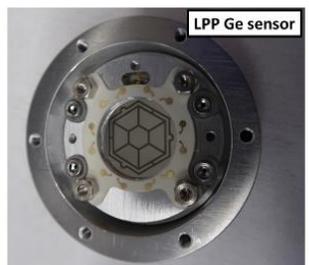
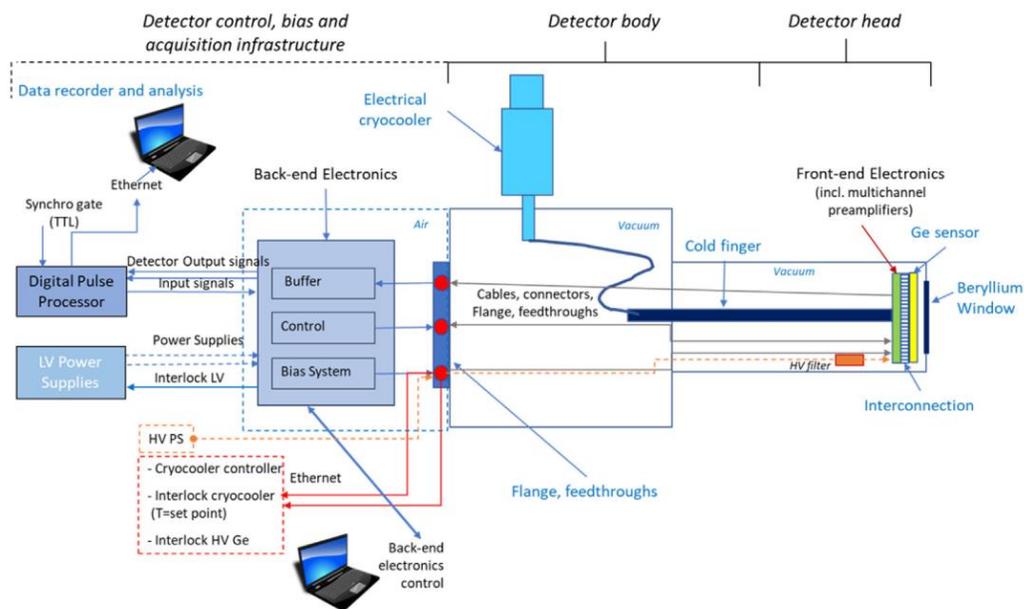
*Xspress3X*

*G. Utica et al., JINST 16 (2021) P07057*

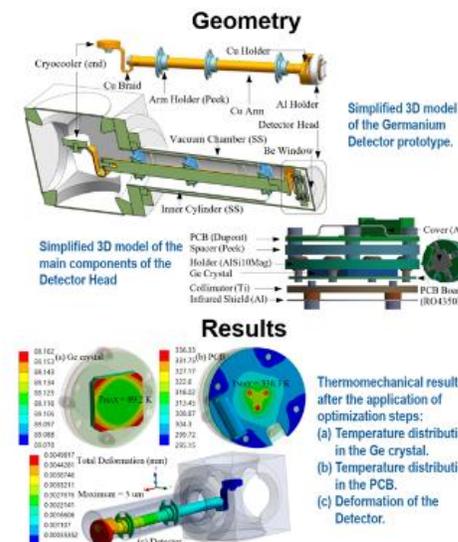
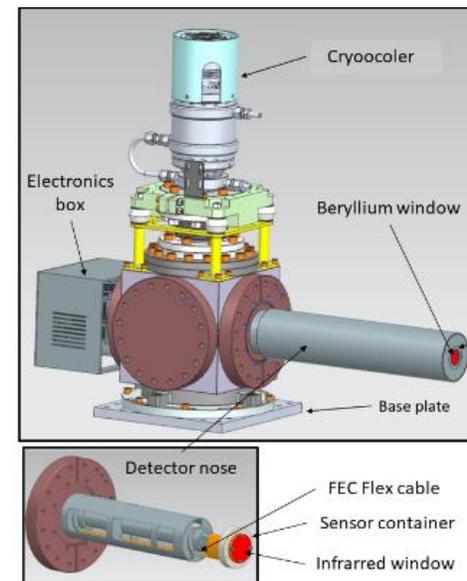
*I. Hafizh et al., JINST 14 (2019) P06027*

- Spectrometer developed by Politecnico Milano (Carlo Fiorini).
- Three spectrometers being integrated in DESY (ID16A, BM8), ESRF (P06) and LFN (DAFNE-LIGHT).
- Main features:
  - Sensors produced by FBX: **16 pixels**, **5 mm pixel size**, thickness of 450  $\mu\text{m}$ , 800  $\mu\text{m}$  or 1000  $\mu\text{m}$
  - 500  $\mu\text{m}$  thick Mo/Zr mask (or Zirconium) to prevent charge sharing. Total collimated area = 324  $\text{mm}^2$
  - Four custom-designed 4-channel CUBE preamplifiers.
  - Two external units for bias and cooling control. Dedicated GUI to monitor & control spectrometer.
  - 16 output signals connected to an external DPP (DANTE, FalconX, Xspress3X/M).





F. Orsini et al., Nucl. Instr. Meth A 1045 (2023) 167600



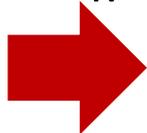
M. Quispe et al, IPAC 2023

Two new multi-element monolithic HPGe detectors for synchrotron applications, keeping a good energy resolution at high count rates (passing from 20 to 250 kcps/mm<sup>2</sup>) in a broad X-ray energy range (5-100 keV)

## Main features:

1. New germanium crystals. Pixels sizes: 5 mm<sup>2</sup> (small) and 20 mm<sup>2</sup> (big).
2. A new full electronic chain (TETRA ASIC, FEC, BEC) has been designed and built.
3. The mechanical design has been optimized using thermal simulations.
4. Xspress4 digital pulse processor will be used to remove charge sharing events.

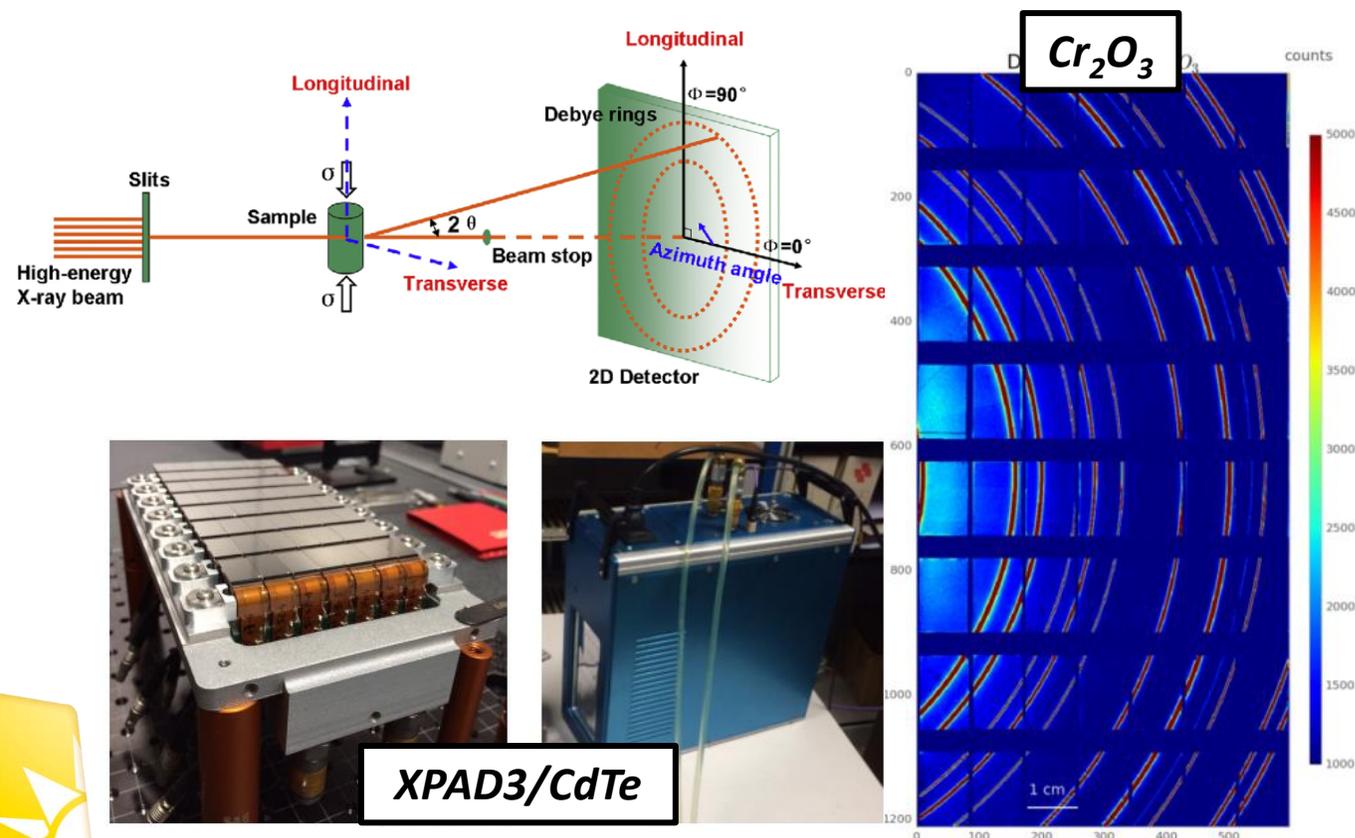
**More details at the poster by Nishu GOYAL (SOLEIL)**



# Diffraction techniques

## X-ray Powder Diffraction (XRPD)

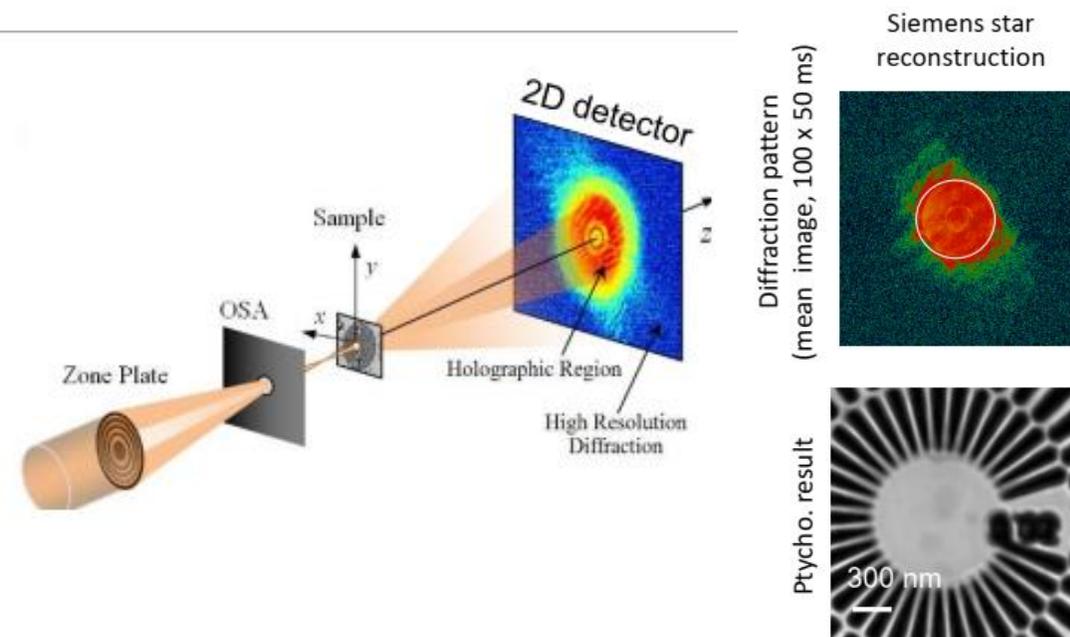
- Technique for **structure characterization of materials**
- The **sample is rotated** so as it randomly arranged. A significant number of each plane of the crystal structure will be in the proper orientation to diffract the X-rays.



F. Cassol et al., JINST 10 (2015) C11010

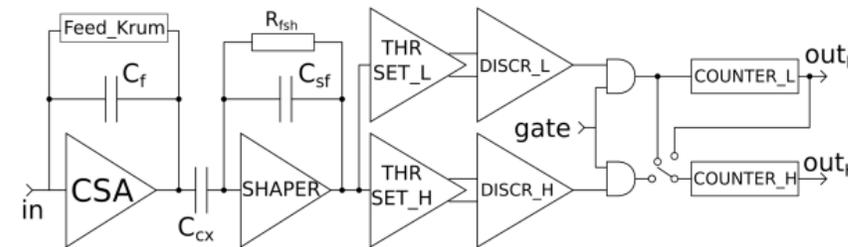
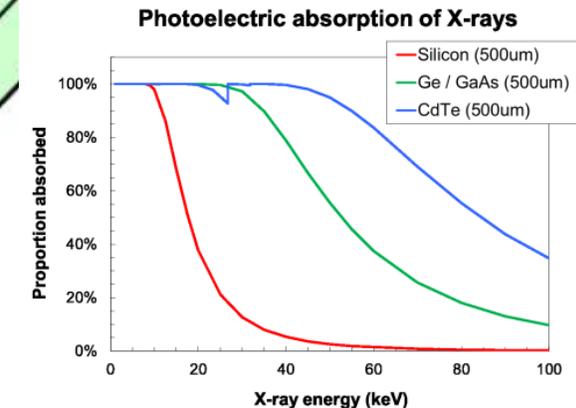
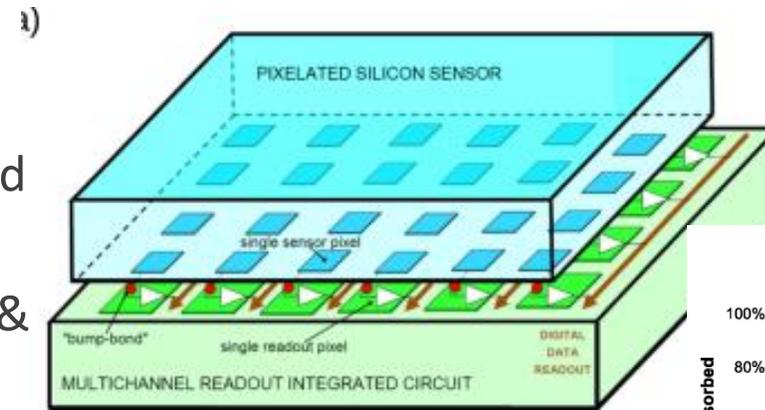
## Ptychography

- Imaging technique based on the coherent scattering of soft X-rays in transmission mode with variable angle.
- The **sample position is scanned** with respect to the incoming coherent beam (the probe) to create a sequential array of overlapping illuminated areas.
- For each position, the coherent diffraction pattern is recorded by a 2D detector in the far-field region.

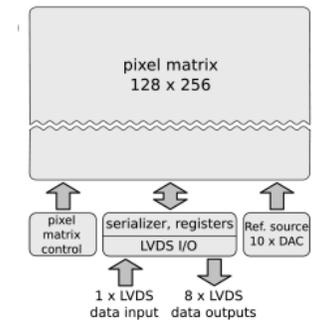


N. Milles et al., Communication Materials 3 (2022) 8

- 2D photon counting detector
- It is composed of a sensor and an ASIC
  - **Sensor:** Material & thickness is chosen according to X-ray energy range
  - **ASIC:** Pixel size, single readout pixel scheme & block diagram are designed according to performance (counting rate, frame rate,...).
- **Detector design:**
  - Large surface (several sensor-ASICs)
  - Compact (global design)
  - Temperature stability (cooling system)
  - Fast frame rate & image reconstruction (firmware, back-end & software design)

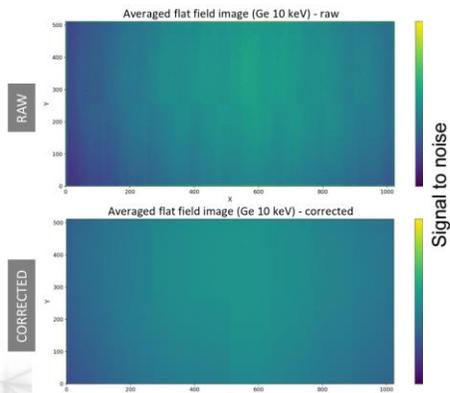


**Single readout pixel scheme of UFXC32 ASIC**

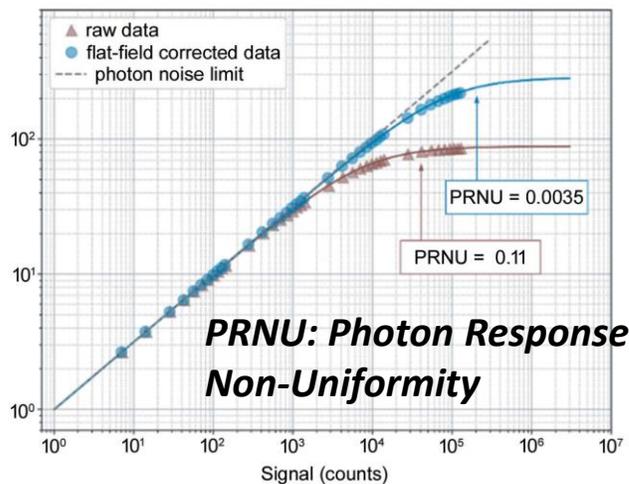


**Simplified block diagram**

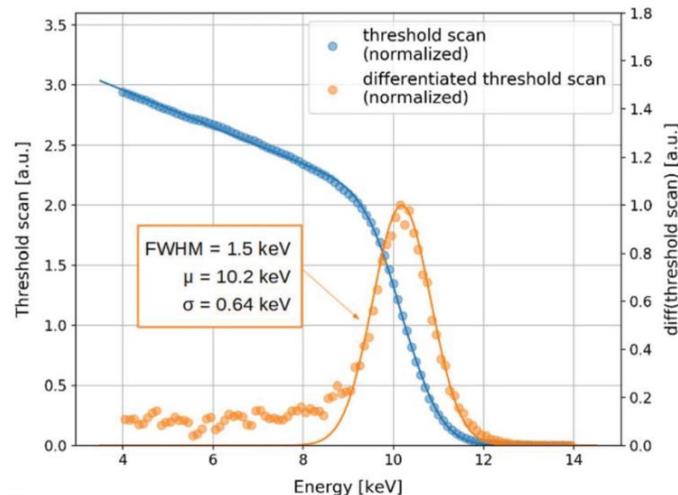
## Flat field correction



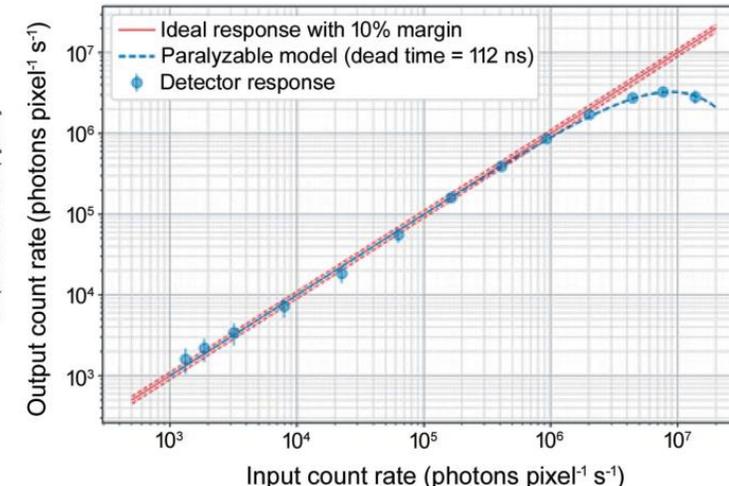
## Signal-to-noise ratio (before & after flat field correction)



## Energy threshold (S-curve)



## Count rate linearity



## Calibration & characterization process:

- Flat field correction & detector homogeneity
- Bad pixel identification (dead, undercounting, good, noisy)
- Signal-to-noise ratio measurement
- Energy resolution (S-curve)
- Modulation Transfer Function
- Counting rate linearity



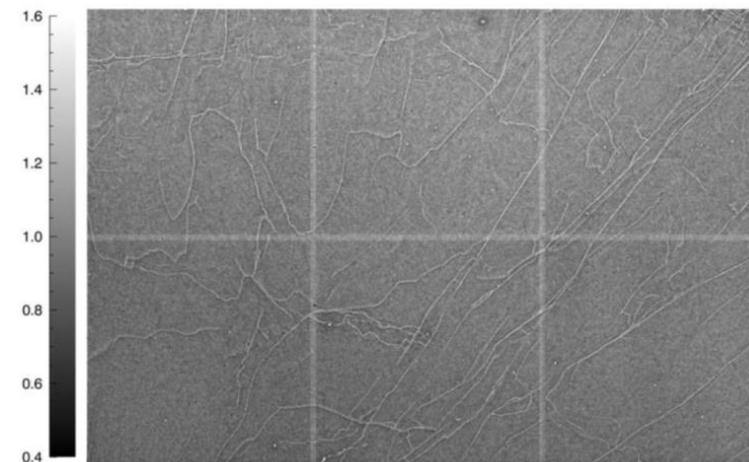
**XSPA-500k detector  
(RIGAKU company)**

- Detection area: **77.8 × 38.9 mm<sup>2</sup>** / Sensor: **Si 320 μm**
- Image size: **1024 × 512 pixels** / Pixel size: **76 × 76 μm<sup>2</sup>**
- Readout ASICs: **16 UFXC** (no inter-chips gaps)
- Framerate: **8.6 kfps @ 16 bits**, 56 kfps @ 2 bits

## Sensor materials:

- CdTe/CdZnTe/GaAs:Cr (for hard X-rays)
  - Large sensor area, uniform, radiation hardness
- LGAD (for soft X-rays, 250 eV - 2 keV)
  - High QE, low entrance window

*Flat field X-ray response*  
**LAMBDA**  
(CdTe 1mm)



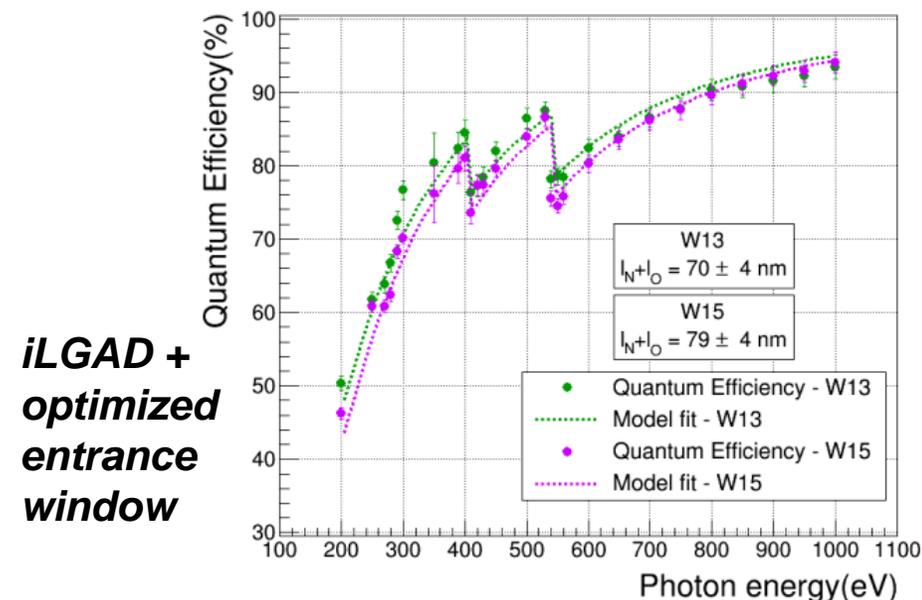
## ASIC development:

- Lower noise -> Lower threshold
- Lower threshold dispersion -> Better flat field
- Increase count rate -> Work at higher flux

## Building readout systems:

- Cooling system -> Stable calibration & operation
- Data-flow optimization -> Increase of fps

*C. Ponchut et al., Rad. Meas. 140 (2021) 106459*



*A. Ligouri et al., JINST 18 (2023) P12006*

	MAXIPIX	LAMBDA	MERLIN	EXCALIBUR
<b>Developer</b>	ESRF	DESY (Spectrum)	Diamond (QD)	Diamond
<b>Chip</b>	Medipix2	Medipix3RX	Medipix3	Medipix3RX
<b>Pixel size</b>	<b>55 <math>\mu\text{m}</math></b>	<b>55 <math>\mu\text{m}</math></b>	<b>55 <math>\mu\text{m}</math></b>	<b>55 <math>\mu\text{m}</math></b>
<b>Sensor</b>	Si 500 $\mu\text{m}$ CdTe 1 mm	Si 300, 500 $\mu\text{m}$ CdTe 1 mm Ga As 500 $\mu\text{m}$	Si 500 $\mu\text{m}$	Si 500 $\mu\text{m}$
<b>Matrix</b>	256 x 256 (1) 512 x 512 (2x2) 1280 x 256 (5x1)	512 x 512 (2x2) 1536 x 1536 (5x5) 4608 x 2560 (18x10)	256 x 256 (1) 512 x 512 (2x2)	2048x512 (8x2)
<b>Frame rate</b>	1.4 kfps	2.0 kfps	100 fps (1) 25 fps (2x2)	100 fps (cont) 1 kfps (burst)



**MAXIPIX**



**LAMBDA**



**MERLIN**



**EXCALIBUR**

	Eiger2 XE-16M	Eiger 2 X 1EM	Pilatus4 XE 4M	Pilatus4 X 1M
<b>Developer</b>	Dectris	Dectris	Dectris	Dectris
<b>Pixel size</b>	<b>75 <math>\mu\text{m}</math></b>	<b>75 <math>\mu\text{m}</math></b>	<b>150 <math>\mu\text{m}</math></b>	<b>150 <math>\mu\text{m}</math></b>
<b>Sensor</b>	Si 450 $\mu\text{m}$	Si 450 $\mu\text{m}$	Si 450 $\mu\text{m}$ Cd 1 mm	Si 450 $\mu\text{m}$ Cd 1 mm
<b>Area</b>	311 x 327 mm <sup>2</sup>	77 x 79 mm <sup>2</sup>	311 x 327 mm <sup>2</sup>	155 x 162 mm <sup>2</sup>
<b>Matrix</b>	4,148 x 4,362	1,028 x 1,062	2,073 x 2,180	1,033 x 1,080
<b>Count rate</b>	10 <sup>7</sup> Hz	10 <sup>7</sup> Hz	10 <sup>7</sup> Hz	10 <sup>7</sup> Hz
<b>Frame rate</b>	550 fps	2250 fps	2000 fps	2000 fps



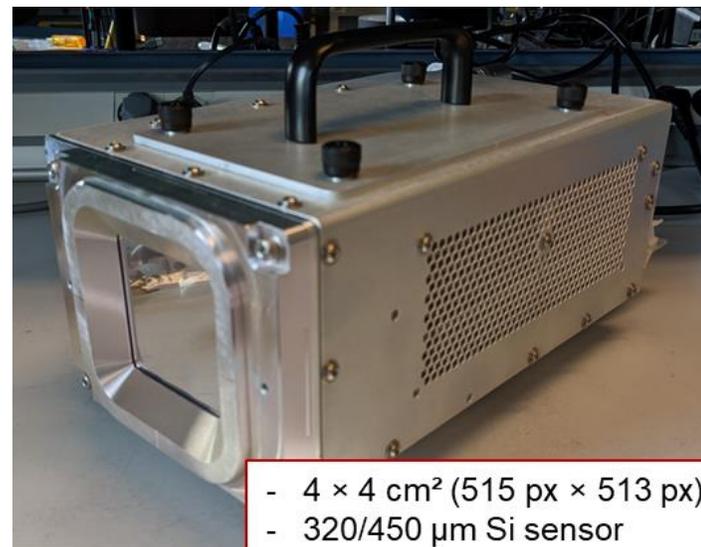
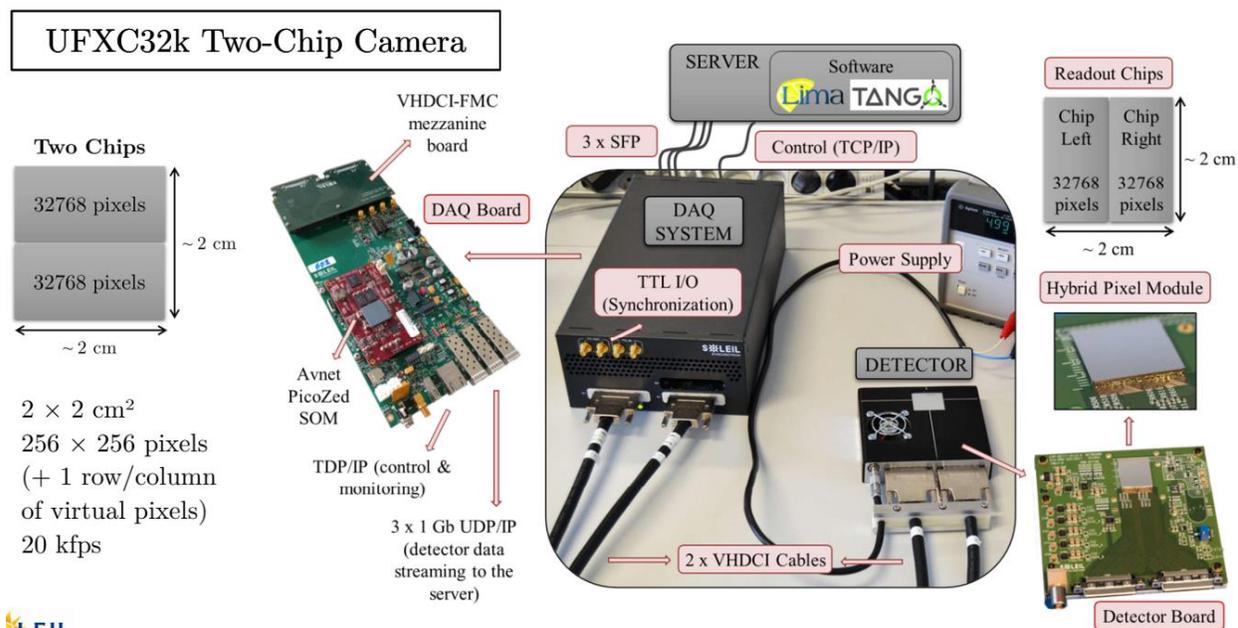
**Eiger2**



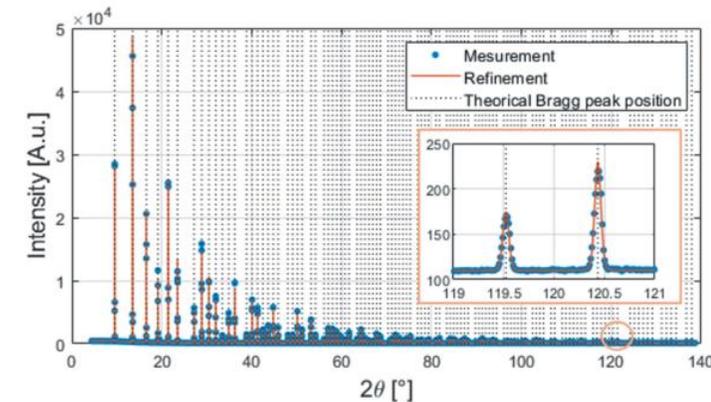
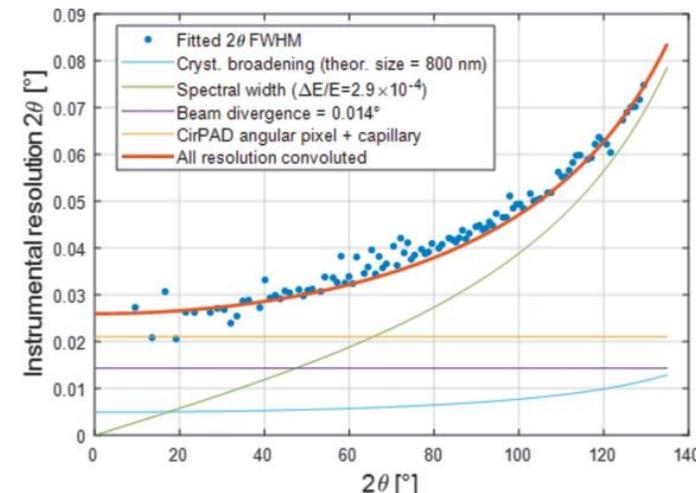
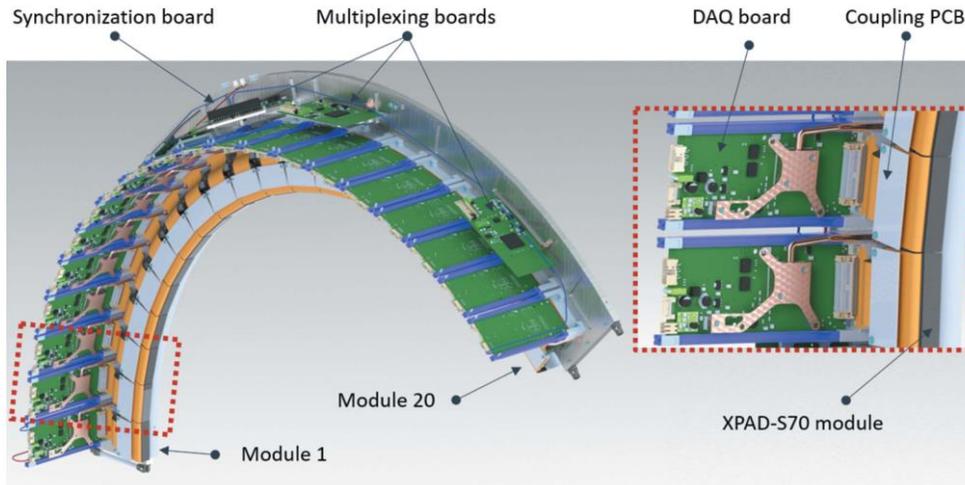
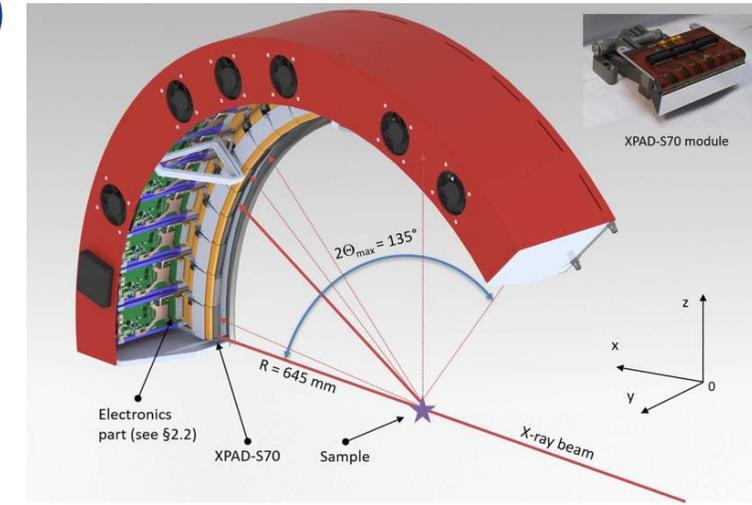
**Pilatus**

*D. Bachiller Perea et al., J. Sync. Rad 27 (2020) 340-350*  
*A. Dawiec et al., IEEE NSS-MIC (2021)*

- SOLEIL R&D in collaboration with **AGH** (Poland).
- Pixel size:  $75 \times 75 \mu\text{m}^2$ , 2 threshold & 2 counters
- Linear count rate up to  $2 \times 10^6$  ph/pixel/sec (max  $10^7$  ph/pixel/sec)
- Different readout modes: standard, continuous and pump-probe-probe
- Two versions: 2 chips (square, rectangular), 8 chips (software being finalized).
- Fully integrated in several beamlines (CRISTAL, SIRIUS, NANOSCOPIUM, ...)

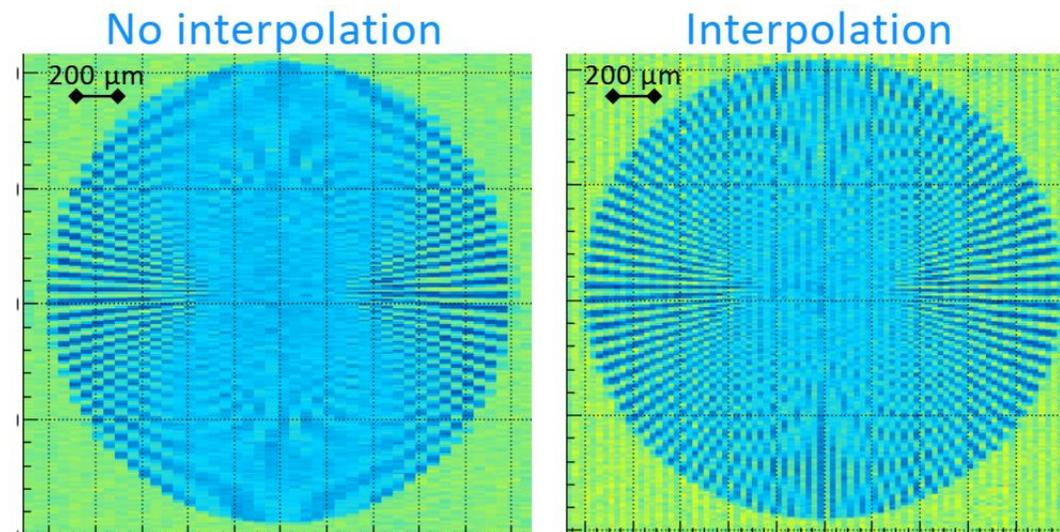


- Diffractometer composed of 20 modules XPAD-S70 (67200 pixels/module) developed for DIFFABS beamline at SOLEIL
  - XPAD-S70: hybrid pixel detector (500  $\mu\text{m}$  Silicon, 130  $\mu\text{m}$  x 130  $\mu\text{m}$  pixel size)
- Main features:
  - X-ray energy range = **7 – 35 keV**
  - Angular acceptance = **6.67° x 1.38°** (1 module) / Resolution = **~0.02°**
  - Frame rate = **250 Hz** (continuous), **700 Hz** (980 frames)
  - Count rate limit = **0.84** (SLOW mode) -  **$2.5 \times 10^6$  ph/sec/pixel** (FAST mode)
  - Defective pixels = **0.02%** (SLOW) - **0.09%** (FAST) / Few hot pixels (0.0001%)



*A. Bergamaschi et al., JSR 17 (2010), 653-668*

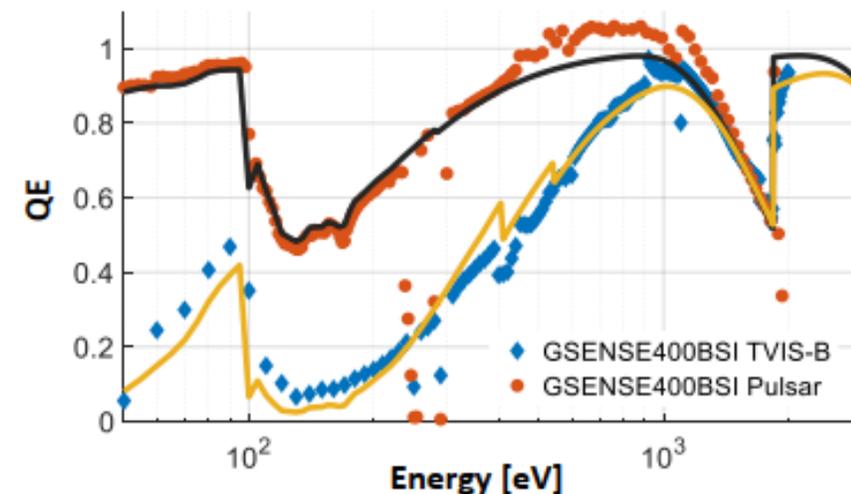
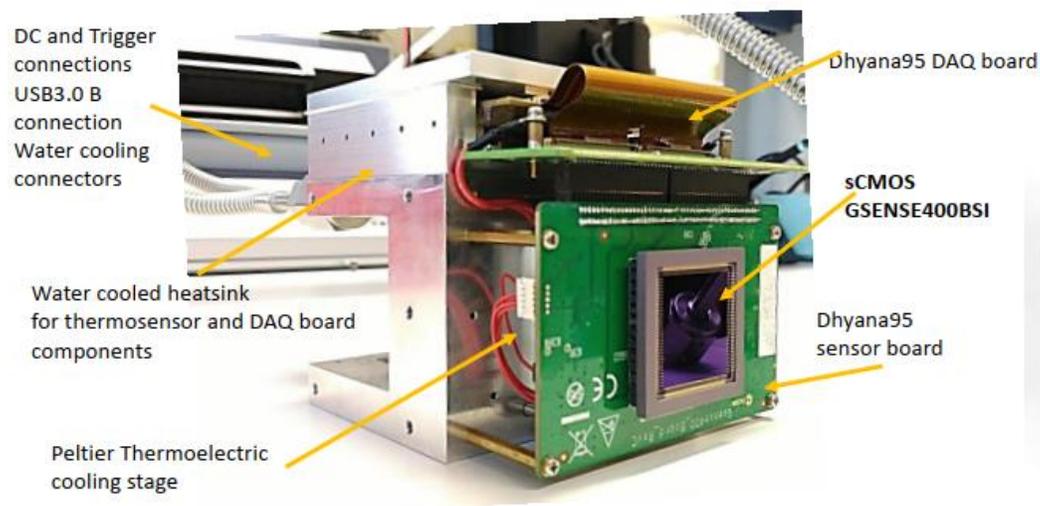
- Diffractometer covering 120 degrees (4 mdeg resolution) composed of 24x2 modules Mythen-III developed for PSI synchrotron
- Features of Mythen-III module:
  - 1280 strips module, 50  $\mu\text{m}$  pitch, 8 mm length
  - Noise level: **350-900 eV (FWHM)** / Threshold dispersion:  **$\sim 20$  eV**
  - Count rate capability: **3.5 – 7.75 MHz** / Frame rate = **400 fps**
  - Three counters with independent gate: **increase of count rate & sub-strip spatial resolution**



*A. Bergamaschi, M. Andrä, et al., JINST 17 (2022) C11012*

- SOLEIL internal development. Commercialized by AXIS photonics
- First version based on TUCSEN Dhyana95 camera (4 Mpx, GSENSE400BSI)
- Features: 2x2 cm<sup>2</sup> sensor size, low noise, large dynamic range, high QE
- Fully integrated in HERMES, SIRIUS & SEXTANTS (~10<sup>-6</sup> mbar, software)
- **Current activities: 6 x 6 cm<sup>2</sup> sensor + spectroscopy (clustering by software)**

Camera specification	
Resolution	2048 x 2048
Pixel size	11 μm x 11 μm
Sensitive area	22.5 mm x 22.5 mm
Shutter type	Rolling shutter
Dark noise	1.7 e <sup>-</sup> (HRD)
Full well charge	85 ke <sup>-</sup> (Low Gain mode)
	30 ke <sup>-</sup> (HDR mode)
	2 ke <sup>-</sup> (High Gain mode)
Frame rate	24 fps (Full frame)
Dark current	> 3 e <sup>-</sup> /s/pix @ -20°C



**More details at the presentation by Kewin DESJARDINS (SOLEIL)**

- Big development of detector based on semiconductor for Synchrotron facilities
  - Sensor -> Uniform response & radiation hardness
  - ASIC -> Small pixels and large dynamic range
  - Firmware -> Reduction of charge sharing for spectroscopy
  - Readout system -> Large area covering, high frame rate
- Detector development is made by synchrotron facilities, research laboratories and private companies
- Synchrotron are pushing detector limits for facilities upgrades